
PART NUMBER**LM4665LDX-G-ROCV**

**Rochester Electronics
Manufactured Components**

Rochester branded components are manufactured using either die/wafers purchased from the original suppliers or Rochester wafers recreated from the original IP. All re-creations are done with the approval of the Original Component Manufacturer. (OCM)

Parts are tested using original factory test programs or Rochester developed test solutions to guarantee product meets or exceeds the OCM data sheet.

Quality Overview

- ISO-9001
- AS9120 certification
- Qualified Manufacturers List (QML) MIL-PRF-38535
 - Class Q Military
 - Class V Space Level

Qualified Suppliers List of Distributors (QSLD)

- Rochester is a critical supplier to DLA and meets all industry and DLA standards.

Rochester Electronics, LLC is committed to supplying products that satisfy customer expectations for quality and are equal to those originally supplied by industry manufacturers.

The original manufacturer's datasheet accompanying this document reflects the performance and specifications of the Rochester manufactured version of this device. Rochester Electronics guarantees the performance of its semiconductor products to the original OCM specifications. 'Typical' values are for reference purposes only. Certain minimum or maximum ratings may be based on product characterization, design, simulation, or sample testing.

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LM4665 Boomer® Audio Power Amplifier Series

Filterless High Efficiency 1W Switching Audio Amplifier

General Description

The LM4665 is a fully integrated single-supply high efficiency switching audio amplifier. It features an innovative modulator that eliminates the LC output filter used with typical switching amplifiers. Eliminating the output filter reduces parts count, simplifies circuit design, and reduces board area. The LM4665 processes analog inputs with a delta-sigma modulation technique that lowers output noise and THD when compared to conventional pulse width modulators.

The LM4665 is designed to meet the demands of mobile phones and other portable communication devices. Operating on a single 3V supply, it is capable of driving 8Ω transducer loads at a continuous average output of 400mW with less than 2%THD+N.

The LM4665 has high efficiency with an 8Ω transducer load compared to a typical Class AB amplifier. With a 3V supply, the IC's efficiency for a 100mW power level is 75%, reaching 80% at 400mW output power.

The LM4665 features a low-power consumption shutdown mode. Shutdown may be enabled by either a logic high or low depending on the mode selection. Connecting the Shutdown Mode pin to either V_{DD} (high) or GND (low) enables the Shutdown pin to be driven in a likewise manner to activate shutdown.

The LM4665 has fixed selectable gain of either 6dB or 12dB. The LM4665 has short circuit protection against a short from the outputs to V_{DD} , GND or across the outputs.

Key Specifications

- Efficiency at 100mW into 8Ω transducer 75%(typ)
- Efficiency at 400mW into 8Ω transducer 80%(typ)
- Total quiescent power supply current (3V) 3mA(typ)
- Total shutdown power supply current (3V) 0.01μA(typ)
- Single supply range (MSOP & LD) 2.7V to 5.5V
- Single supply range (ITL) (Note 11) 2.7V to 3.8V

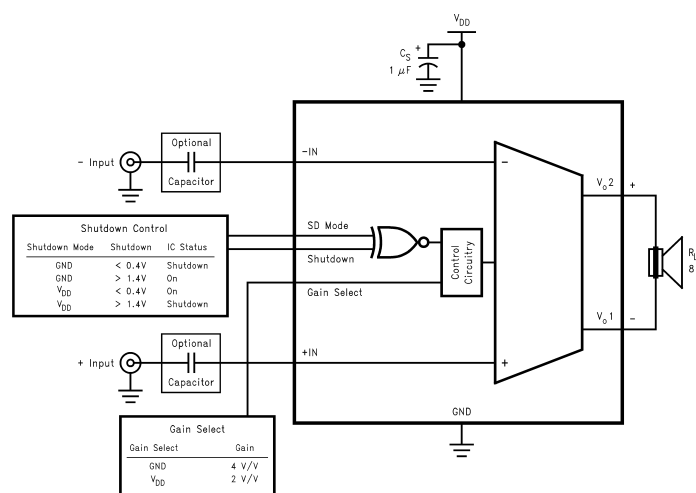
Features

- No output filter required for inductive transducers
- Selectable gain of 6dB (2V/V) or 12dB (4V/V)
- Very fast turn on time: 5ms (typ)
- User selectable shutdown High or Low logic level
- Minimum external components
- "Click and pop" suppression circuitry
- Micro-power shutdown mode
- Short circuit protection
- micro SMD, LLP, and MSOP packages (no heat sink required)

Applications

- Mobile phones
- PDAs
- Portable electronic devices

Typical Application

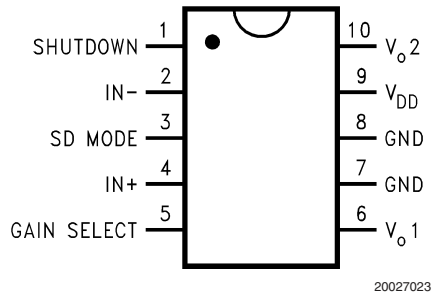


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FIGURE 1. Typical Audio Amplifier Application Circuit

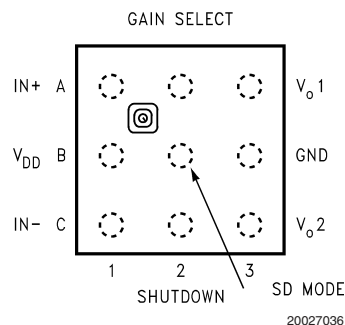
Connection Diagrams

Mini Small Outline (MSOP) Package



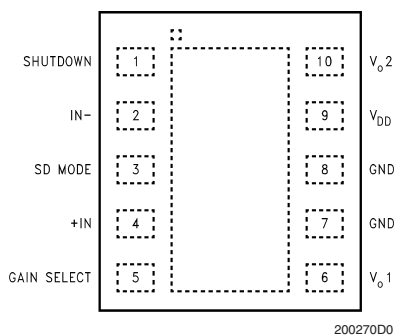
Top View
Order Number LM4665MM
See NS Package Number MUB10A

9 Bump micro SMD Package



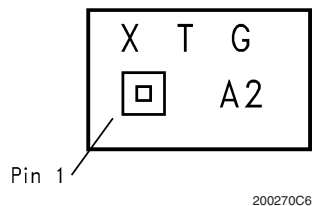
Top View
Order Number LM4665ITL, LM4665ITLX
See NS Package Number TLA09AAA

LLP Package



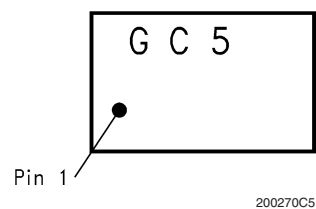
Top View
Order Number LM4665LD
See NS Package Number LDA10B

micro SMD Marking



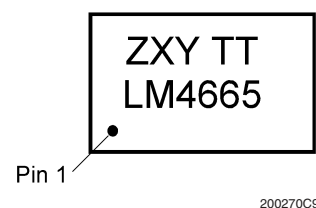
Top View
X - Date Code
T - Die Traceability
G - Boomer Family
A2 - LM4665ITL

MSOP Marking



Top View
G - Boomer Family
C5 - LM4665MM

LLP Marking



Top View
Z - Plant Code
XY - Date Code
TT - Die Traceability
Bottom Line-Part Number

Absolute Maximum Ratings (Notes 1,

2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Supply Voltage (Note 1)	6.0V
Storage Temperature	-65°C to +150°C
Voltage at Any Input Pin	$V_{DD} + 0.3V \geq V \geq GND - 0.3V$
Power Dissipation (Note 3)	Internally Limited
ESD Susceptibility (Note 4)	2.0kV
ESD Susceptibility (Note 5)	200V
Junction Temperature (T_J)	150°C
Thermal Resistance	
θ_{JA} (MSOP)	190°C/W

θ_{JC} (MSOP)	56°C/W
θ_{JA} (micro SMD)	180°C/W
θ_{JA} (LLP) (Note 10)	63°C/W
θ_{JC} (LLP) (Note 10)	12°C/W

Soldering Information

See AN-1112 "microSMD Wafers Level Chip Scale Package."

Operating Ratings (Note 2)**Temperature Range**

$T_{MIN} \leq T_A \leq T_{MAX}$	$-40^\circ\text{C} \leq T_A \leq 85^\circ\text{C}$
Supply Voltage (MSOP & LD)	$2.7V \leq V_{DD} \leq 5.5V$
Supply Voltage (ITL) (Note 11)	$2.7V \leq V_{DD} \leq 3.8V$

Electrical Characteristics $V_{DD} = 5V$ (Notes 1, 2, 11)

The following specifications apply for $V_{DD} = 5V$, $R_L = 8\Omega + 33\mu H$, measurement bandwidth is <10Hz - 22kHz unless otherwise specified. Limits apply for $T_A = 25^\circ\text{C}$.

Symbol	Parameter	Conditions	LM4665		Units (Limits)
			Typical	Limit	
			(Note 6)	(Notes 7, 8)	
I_{DD}	Quiescent Power Supply Current	$V_{IN} = 0V$, No Load	14		mA
		$V_{IN} = 0V$, $8\Omega + 22\mu H$ Load	14.5		mA
I_{SD}	Shutdown Current	$V_{SD} = V_{SD \text{ Mode}}$ (Note 9)	0.1	5.0	μA (max)
V_{SDIH}	Shutdown Voltage Input High	$V_{SD \text{ Mode}} = V_{DD}$	1.2	1.4	V (min)
V_{SDIL}	Shutdown Voltage Input Low	$V_{SD \text{ Mode}} = V_{DD}$	1.1	0.4	V (max)
V_{SDIH}	Shutdown Voltage Input High	$V_{SD \text{ Mode}} = GND$	1.2	1.4	V (min)
V_{SDIL}	Shutdown Voltage Input Low	$V_{SD \text{ Mode}} = GND$	1.1	0.4	V (max)
V_{GSIH}	Gain Select Input High		1.2	1.4	V (min)
V_{GSIL}	Gain Select Input Low		1.1	0.4	V (max)
A_V	Closed Loop Gain	$V_{\text{Gain Select}} = V_{DD}$	6	5.5 6.5	dB (min) dB (max)
		$V_{\text{Gain Select}} = GND$	12	11.5 12.5	dB (min) dB (max)
V_{OS}	Output Offset Voltage		10		mV
T_{WU}	Wake-up Time		5		ms
P_o	Output Power	THD+N = 3% (max), $f_{IN} = 1\text{kHz}$	1.4		W
THD+N	Total Harmonic Distortion+Noise	$P_O = 400\text{mW}_{RMS}$, $f_{IN} = 1\text{kHz}$	0.8		%
R_{IN}	Differential Input Resistance	$V_{\text{Gain Select}} = V_{DD}$, Gain = 6dB	100		k Ω
		$V_{\text{Gain Select}} = GND$, Gain = 12dB	65		k Ω
PSRR	Power Supply Rejection Ratio	$V_{\text{Ripple}} = 100\text{mV}_{RMS}$, $f_{\text{Ripple}} = 217\text{Hz}$, $A_V = 6\text{dB}$ Inputs Terminated	52		dB
CMRR	Common Mode Rejection Ratio	$V_{\text{Ripple}} = 100\text{mV}_{RMS}$, $f_{\text{Ripple}} = 217\text{Hz}$, $A_V = 6\text{dB}$	43		dB
e_N	Output Noise Voltage	A-Weighted filter, $V_{IN} = 0V$	350		μV

Electrical Characteristics $V_{DD} = 3V$ (Notes 1, 2)

The following specifications apply for $V_{DD} = 3V$, and $R_L = 8\Omega + 33\mu H$, measurement bandwidth is $<10Hz - 22kHz$ unless otherwise specified. Limits apply for $T_A = 25^\circ C$.

Symbol	Parameter	Conditions	LM4665		Units (Limits)
			Typical	Limit	
			(Note 6)	(Notes 7, 8)	
I_{DD}	Quiescent Power Supply Current	$V_{IN} = 0V$, No Load $V_{IN} = 0V$, $8\Omega + 22\mu H$ Load	3.0 3.5	7.0	mA (max) mA
I_{SD}	Shutdown Current	$V_{SD} = V_{SD Mode}$ (Note 9)	0.01	5.0	μA (max)
V_{SDIH}	Shutdown Voltage Input High	$V_{SD Mode} = V_{DD}$	1.0	1.4	V (min)
V_{SDIL}	Shutdown Voltage Input Low	$V_{SD Mode} = V_{DD}$	0.8	0.4	V (max)
V_{SDIH}	Shutdown Voltage Input High	$V_{SD Mode} = GND$	1.0	1.4	V (min)
V_{SDIL}	Shutdown Voltage Input Low	$V_{SD Mode} = GND$	0.8	0.4	V (max)
V_{GSIH}	Gain Select Input High		1.0	1.4	V (min)
V_{GSIL}	Gain Select Input Low		0.8	0.4	V (max)
A_V	Closed Loop Gain	$V_{Gain Select} = V_{DD}$	6	5.5 6.5	dB (min) dB (max)
A_V	Closed Loop Gain	$V_{Gain Select} = GND$	12	11.5 12.5	dB (min) dB (max)
V_{OS}	Output Offset Voltage		10		mV
T_{WU}	Wake-up Time		5		ms
P_O	Output Power	THD+N = 2% (max), $f_{IN} = 1kHz$	400	350	mW (min)
THD+N	Total Harmonic Distortion+Noise	$P_O = 100mW_{RMS}$, $f_{IN} = 1kHz$	0.4		% (max)
R_{IN}	Differential Input Resistance	$V_{Gain Select} = V_{DD}$, Gain = 6dB	100		$k\Omega$
		$V_{Gain Select} = GND$, Gain = 12dB	65		$k\Omega$
PSRR	Power Supply Rejection Ratio	$V_{Ripple} = 100mV_{RMS}$, $f_{Ripple} = 217Hz$, $A_V = 6dB$, Inputs Terminated	52		dB
CMRR	Common Mode Rejection Ratio	$V_{Ripple} = 100mV_{RMS}$, $f_{Ripple} = 217Hz$, $A_V = 6dB$	39		dB
e_N	Output Noise Voltage	A-Weighted filter, $V_{IN} = 0V$	350		μV

Note 1: All voltages are measured with respect to the ground pin, unless otherwise specified.

Note 2: *Absolute Maximum Ratings* indicate limits beyond which damage to the device may occur. *Operating Ratings* indicate conditions for which the device is functional, but do not guarantee specific performance limits. *Electrical Characteristics* state DC and AC electrical specifications under particular test conditions which guarantee specific performance limits. This assumes that the device is within the Operating Ratings. Specifications are not guaranteed for parameters where no limit is given, however, the typical value is a good indication of device performance.

Note 3: The maximum power dissipation must be derated at elevated temperatures and is dictated by T_{JMAX} , θ_{JA} , and the ambient temperature T_A . The maximum allowable power dissipation is $P_{DMAX} = (T_{JMAX} - T_A)/\theta_{JA}$ or the number given in Absolute Maximum Ratings, whichever is lower. For the LM4665, $T_{JMAX} = 150^\circ C$. See the **Efficiency and Power Dissipation versus Output Power** curves for more information.

Note 4: Human body model, 100 pF discharged through a 1.5 k Ω resistor.

Note 5: Machine Model, 220 pF–240 pF discharged through all pins.

Note 6: Typical specifications are specified at $25^\circ C$ and represent the parametric norm.

Note 7: Tested limits are guaranteed to National's AOQL (Average Outgoing Quality Level).

Note 8: Datasheet min/max specification limits are guaranteed by design, test, or statistical analysis.

Note 9: Shutdown current is measured in a normal room environment. Exposure to direct sunlight will increase I_{SD} by a maximum of 2 μA . The Shutdown Mode pin should be connected to V_{DD} or GND and the Shutdown pin should be driven as close as possible to V_{DD} or GND for minimum shutdown current and the best THD performance in PLAY mode. See the **Application Information** section under SHUTDOWN FUNCTION for more information.

Note 10: The exposed-DAP of the LDA10B package should be electrically connected to GND.

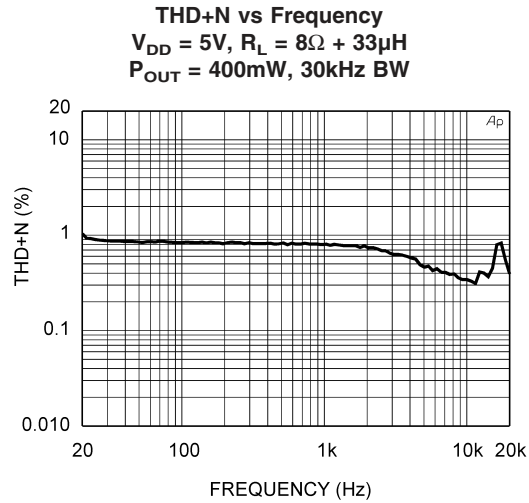
Note 11: The LM4665 in the micro SMD package (ITL) has an operating range of 2.7V - 3.8V for 8 Ω speaker loads. The supply range may be increased as speaker impedance is increased. It is not recommended that 4 Ω loads be used with the micro SMD package. To increase the supply voltage operating range, see Figure 2 and INCREASING SUPPLY VOLTAGE RANGE in the **Application Information** section for more information.

External Components Description

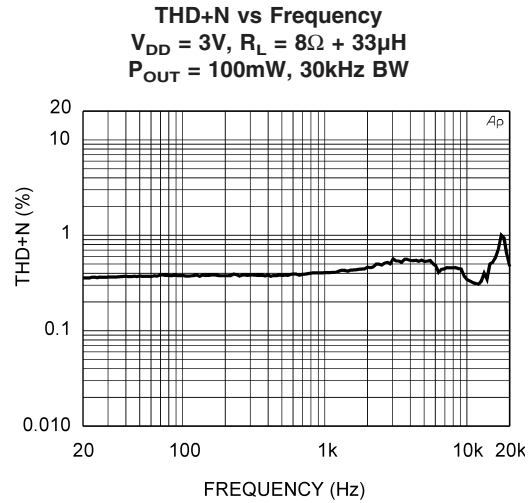
(Figure 1)

Components		Functional Description
1.	C_S	Supply bypass capacitor which provides power supply filtering. Refer to the Power Supply Bypassing section for information concerning proper placement and selection of the supply bypass capacitor.

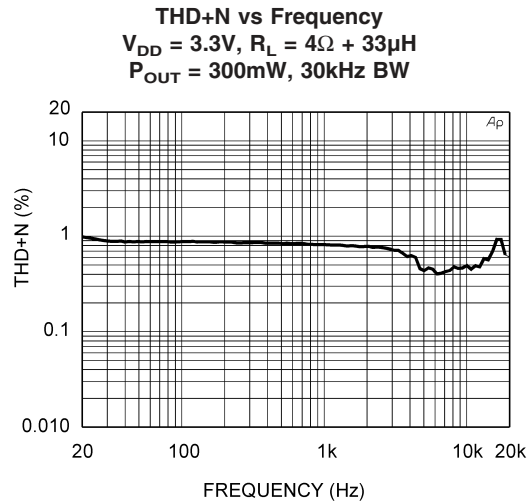
Typical Performance Characteristics



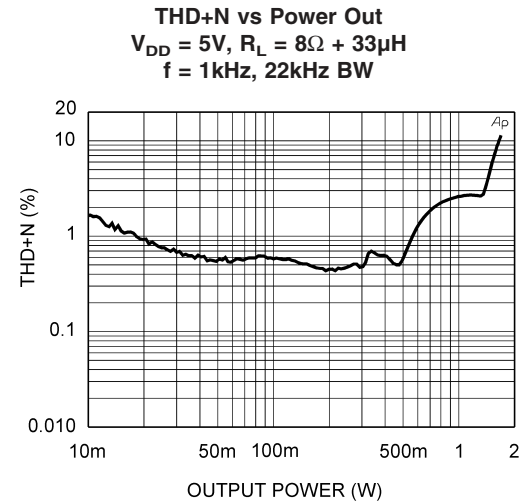
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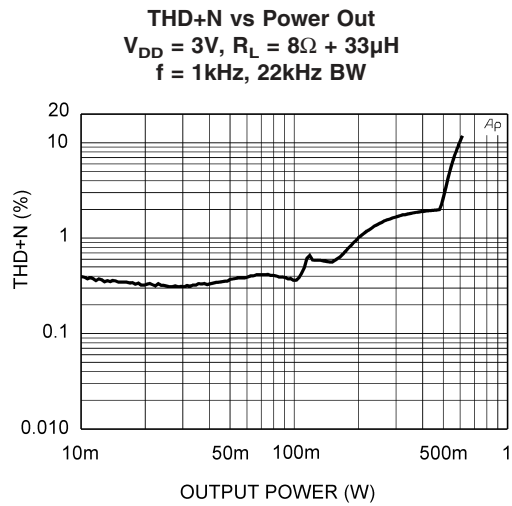
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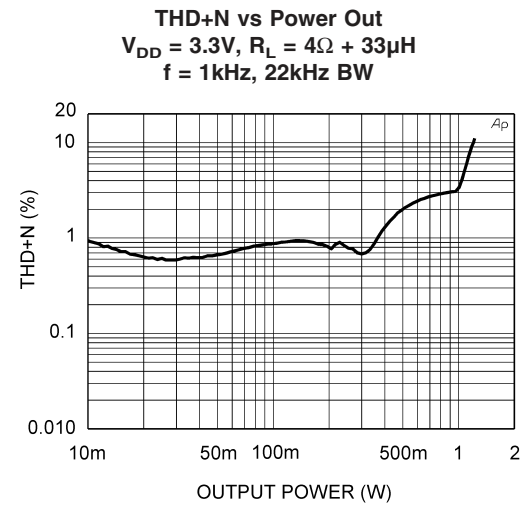
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200270D5



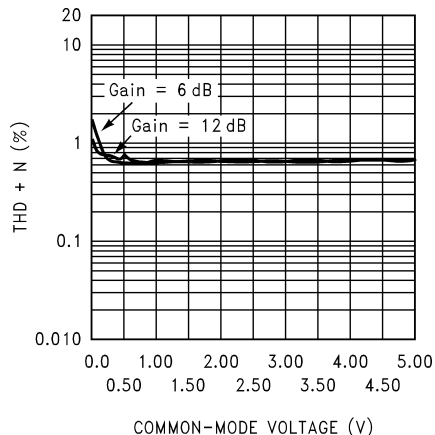
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200270E1

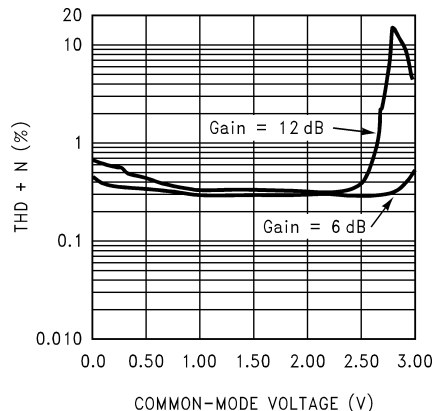
Typical Performance Characteristics (Continued)

THD+N vs Common-Mode Voltage
 $V_{DD} = 5V$, $R_L = 8\Omega + 33\mu H$, $f = 1kHz$
 $P_{OUT} = 400mW$, 22kHz BW



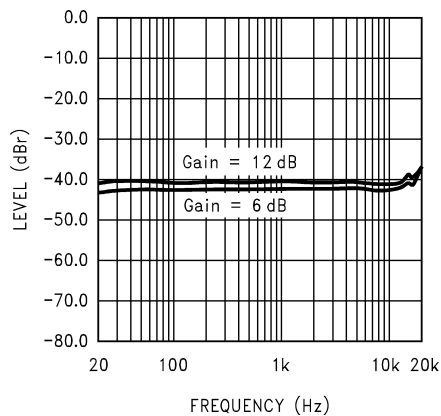
20027032

THD+N vs Common-Mode Voltage
 $V_{DD} = 3V$, $R_L = 8\Omega + 33\mu H$, $f = 1kHz$
 $P_{OUT} = 100mW$, 22kHz BW



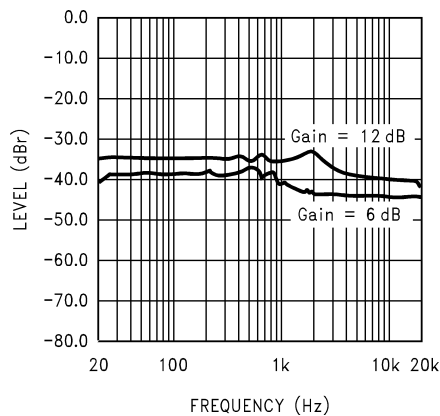
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CMRR vs Frequency
 $V_{DD} = 5V$, $R_L = 8\Omega + 33\mu H$
 $V_{CM} = 100mV_{RMS}$ Sine Wave, 80kHz BW



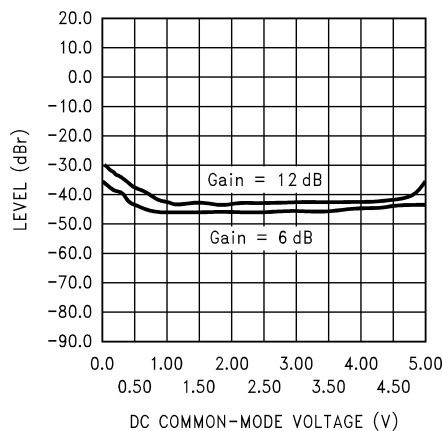
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CMRR vs Frequency
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 $V_{CM} = 100mV_{RMS}$ Sine Wave, 80kHz BW



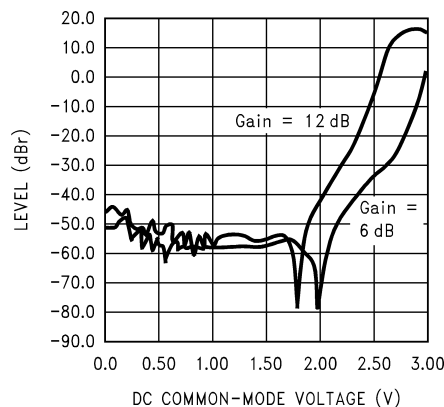
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PSRR vs DC Common-Mode Voltage
 $V_{DD} = 5V$, $R_L = 8\Omega + 33\mu H$
 $V_{Ripple} = 100mV_{RMS}$, $f_{Ripple} = 217Hz$ Sine Wave



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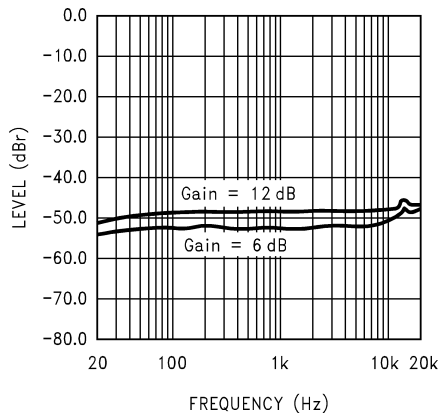
PSRR vs DC Common-Mode Voltage
 $V_{DD} = 3V$, $R_L = 8\Omega + 33\mu H$
 $V_{Ripple} = 100mV_{RMS}$, $f_{Ripple} = 217Hz$ Sine Wave



20027096

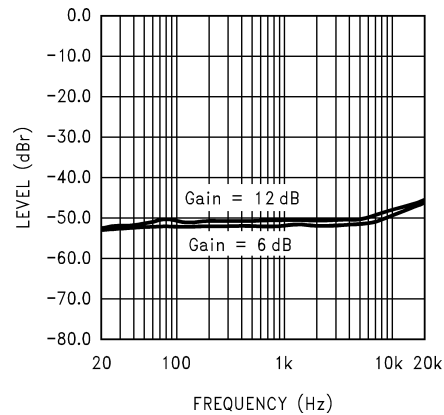
Typical Performance Characteristics (Continued)

PSRR vs Frequency
 $V_{DD} = 5V$, $R_L = 8\Omega + 33\mu H$
 $V_{CM} = 100mV_{RMS}$ Sine Wave, 22kHz BW



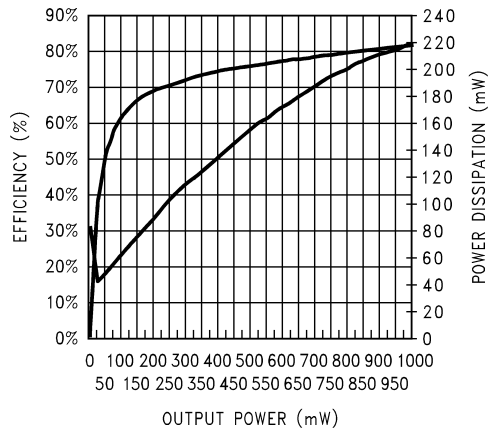
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PSRR vs Frequency
 $V_{DD} = 3V$, $R_L = 8\Omega + 33\mu H$
 $V_{CM} = 100mV_{RMS}$ Sine Wave, 22kHz BW



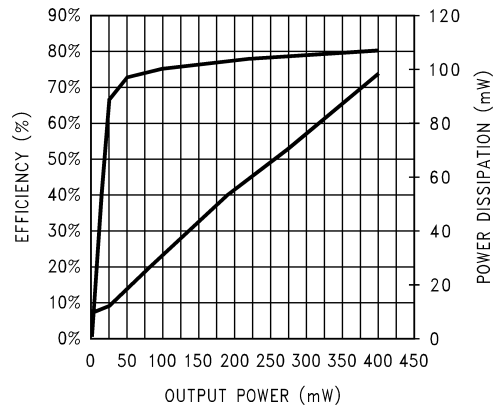
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Efficiency (top trace) and Power Dissipation (bottom trace) vs Output Power
 $V_{DD} = 5V$, $R_L = 8\Omega + 33\mu H$, $f = 1kHz$, THD < 3%



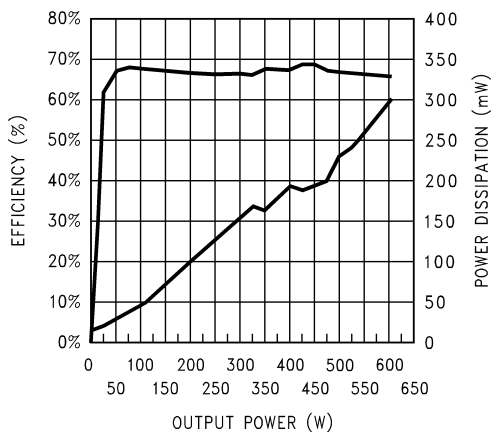
200270A2

Efficiency (top trace) and Power Dissipation (bottom trace) vs Output Power
 $V_{DD} = 3V$, $R_L = 8\Omega + 33\mu H$, $f = 1kHz$, THD < 2%



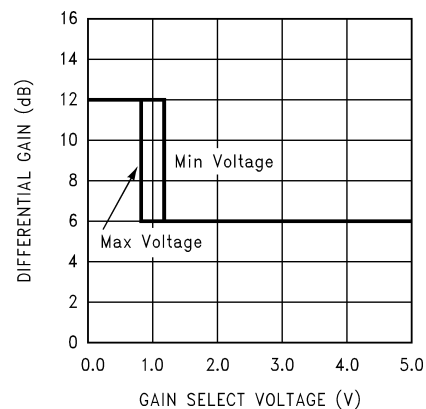
200270A1

Efficiency (top trace) and Power Dissipation (bottom trace) vs Output Power
 $V_{DD} = 3.3V$, $R_L = 4\Omega + 33\mu H$, $f = 1kHz$, THD < 2%



200270A5

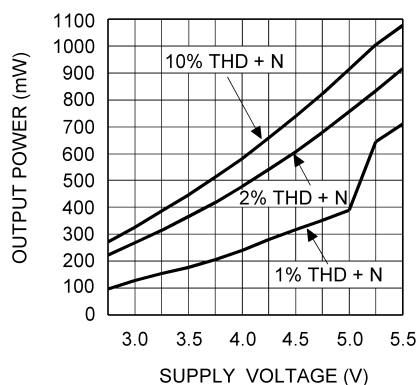
Gain Threshold Voltages
 $V_{DD} = 3V - 5V$



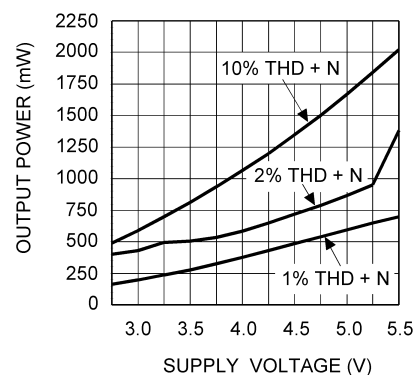
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Typical Performance Characteristics (Continued)

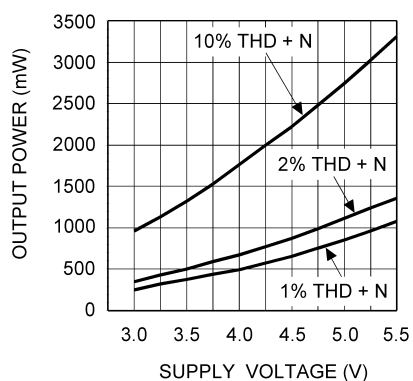
Output Power vs Supply Voltage
 $R_L = 16\Omega + 33\mu H$, $f = 1\text{kHz}$



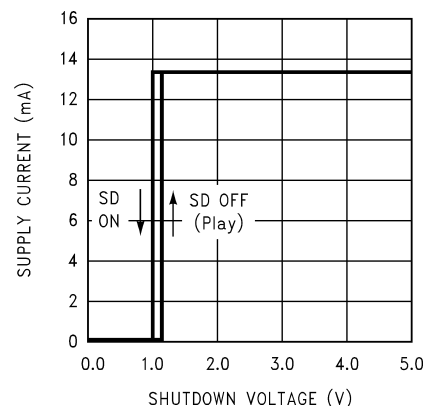
Output Power vs Supply Voltage
 $R_L = 8\Omega + 33\mu H$, $f = 1\text{kHz}$



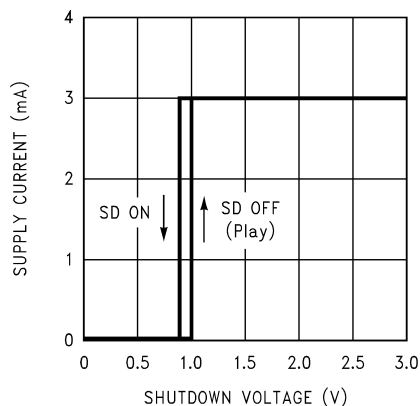
Output Power vs Supply Voltage
 $R_L = 4\Omega + 33\mu H$, $f = 1\text{kHz}$



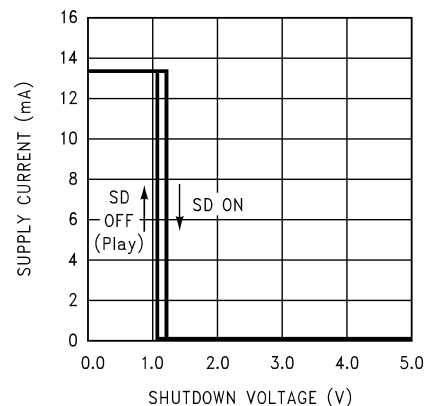
Shutdown Hysteresis Voltage
 $V_{DD} = 5\text{V}$, SD Mode = GND (SD Low)



Shutdown Hysteresis Voltage
 $V_{DD} = 3\text{V}$, SD Mode = GND (SD Low)

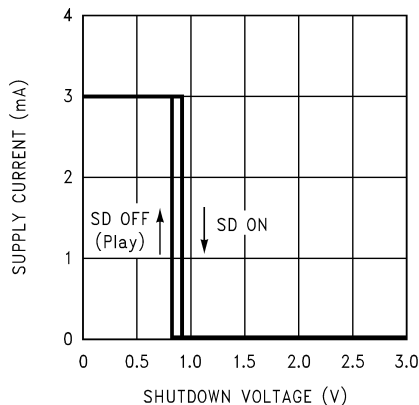


Shutdown Hysteresis Voltage
 $V_{DD} = 5\text{V}$, SD Mode = GND (SD High)



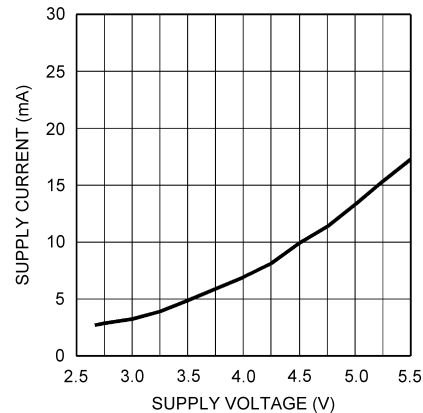
Typical Performance Characteristics (Continued)

Shutdown Hysteresis Voltage
 $V_{DD} = 3V$, SD Mode = GND (SD High)



200270B0

Supply Current vs Supply Voltage
 $R_L = 8\Omega + 33\mu H$



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Application Information

GENERAL AMPLIFIER FUNCTION

The output signals generated by the LM4665 consist of two, BTL connected, output signals that pulse momentarily from near ground potential to V_{DD} . The two outputs can pulse independently with the exception that they both may never pulse simultaneously as this would result in zero volts across the BTL load. The minimum width of each pulse is approximately 160ns. However, pulses on the same output can occur sequentially, in which case they are concatenated and appear as a single wider pulse to achieve an effective 100% duty cycle. This results in maximum audio output power for a given supply voltage and load impedance. The LM4665 can achieve much higher efficiencies than class AB amplifiers while maintaining acceptable THD performance.

The short (160ns) drive pulses emitted at the LM4665 outputs means that good efficiency can be obtained with minimal load inductance. The typical transducer load on an audio amplifier is quite reactive (inductive). For this reason, the load can act as its own filter, so to speak. This "filter-less" switching amplifier/transducer load combination is much more attractive economically due to savings in board space and external component cost by eliminating the need for a filter.

POWER DISSIPATION AND EFFICIENCY

In general terms, efficiency is considered to be the ratio of useful work output divided by the total energy required to produce it with the difference being the power dissipated, typically, in the IC. The key here is "useful" work. For audio systems, the energy delivered in the audible bands is considered useful including the distortion products of the input signal. Sub-sonic (DC) and super-sonic components (>22kHz) are not useful. The difference between the power flowing from the power supply and the audio band power being transduced is dissipated in the LM4665 and in the transducer load. The amount of power dissipation in the LM4665 is very low. This is because the ON resistance of the switches used to form the output waveforms is typically less than 0.25Ω . This leaves only the transducer load as a po-

tential "sink" for the small excess of input power over audio band output power. The LM4665 dissipates only a fraction of the excess power requiring no additional PCB area or copper plane to act as a heat sink.

DIFFERENTIAL AMPLIFIER EXPLANATION

As logic supply voltages continue to shrink, designers are increasingly turning to differential analog signal handling to preserve signal to noise ratios with restricted voltage swing. The LM4665 is a fully differential amplifier that features differential input and output stages. A differential amplifier amplifies the difference between the two input signals. Traditional audio power amplifiers have typically offered only single-ended inputs resulting in a 6dB reduction in signal to noise ratio relative to differential inputs. The LM4665 also offers the possibility of DC input coupling which eliminates the two external AC coupling, DC blocking capacitors. The LM4665 can be used, however, as a single ended input amplifier while still retaining its fully differential benefits. In fact, completely unrelated signals may be placed on the input pins. The LM4665 simply amplifies the difference between the signals. A major benefit of a differential amplifier is the improved common mode rejection ratio (CMRR) over single input amplifiers. The common-mode rejection characteristic of the differential amplifier reduces sensitivity to ground offset related noise injection, especially important in high noise applications.

PCB LAYOUT CONSIDERATIONS

As output power increases, interconnect resistance (PCB traces and wires) between the amplifier, load and power supply create a voltage drop. The voltage loss on the traces between the LM4665 and the load results in lower output power and decreased efficiency. Higher trace resistance between the supply and the LM4665 has the same effect as a poorly regulated supply, increase ripple on the supply line also reducing the peak output power. The effects of residual trace resistance increases as output current increases due to higher output power, decreased load impedance or both. To maintain the highest output voltage swing and corresponding peak output power, the PCB traces that connect

Application Information (Continued)

the output pins to the load and the supply pins to the power supply should be as wide as possible to minimize trace resistance.

The rising and falling edges are necessarily short in relation to the minimum pulse width (160ns), having approximately 2ns rise and fall times, typical, depending on parasitic output capacitance. The inductive nature of the transducer load can also result in overshoot on one or both edges, clamped by the parasitic diodes to GND and V_{DD} in each case. From an EMI standpoint, this is an aggressive waveform that can radiate or conduct to other components in the system and cause interference. It is essential to keep the power and output traces short and well shielded if possible. Use of ground planes, beads, and micro-strip layout techniques are all useful in preventing unwanted interference.

POWER SUPPLY BYPASSING

As with any power amplifier, proper supply bypassing is critical for low noise performance and high power supply rejection ratio (PSRR). The capacitor (C_S) location should be as close as possible to the LM4665. Typical applications employ a voltage regulator with a 10 μ F and a 0.1 μ F bypass capacitors that increase supply stability. These capacitors do not eliminate the need for bypassing on the supply pin of the LM4665. A 1 μ F tantalum capacitor is recommended.

SHUTDOWN FUNCTION

In order to reduce power consumption while not in use, the LM4665 contains shutdown circuitry that reduces current draw to less than 0.01 μ A. In addition, the LM4665 contains a Shutdown Mode pin allowing the designer to designate whether the shutdown circuitry is activated by either a High level logic signal or a Low level logic signal. The Shutdown Mode pin should be permanently connected to either GND (Low) or V_{DD} (High). The LM4665 may then be placed into shutdown by toggling the Shutdown pin to the same state as the Shutdown Mode pin. For simplicity's sake, this is called "Shutdown same", as the LM4665 enters into a shutdown state whenever the two pins are in the same logic state. The trigger point for either shutdown high or shutdown low is shown as a typical value in the Electrical Characteristics Tables and in the Shutdown Hysteresis Voltage graphs found in the **Typical Performance Characteristics** section. It is best to switch between ground and supply for minimum current usage while in the shutdown state. While the LM4665 may be disabled with shutdown voltages in between ground and supply, the idle current will be greater than the typical 0.01 μ A value. Increased THD may also be observed with voltages greater than GND and less than V_{DD} on the Shutdown pin when in PLAY mode.

The LM4665 has an internal resistor connected between the Shutdown Mode and Shutdown pins. The purpose of this resistor is to eliminate any unwanted state changes when the Shutdown pin is floating, as long as the Shutdown Mode pin is connected to GND or V_{DD} . When the Shutdown Mode pin is properly connected, the LM4665 will enter the shutdown state when the Shutdown pin is left floating or if not floating, when the shutdown voltage has crossed the corresponding threshold for the logic level assigned by the Shutdown Mode pin voltage. To minimize the supply current while in the shutdown state, the Shutdown pin should be driven to the same potential as the Shutdown Mode pin or left floating. The amount of additional current due to the internal shutdown resistor can be found by Equation (1) below.

$$(V_{SD \text{ MODE}} - V_{SD}) / 60k\Omega \quad (1)$$

With only a 0.5V difference between the Shutdown Mode voltage and the Shutdown voltage an additional 8.3 μ A of current will be drawn while in the shutdown state.

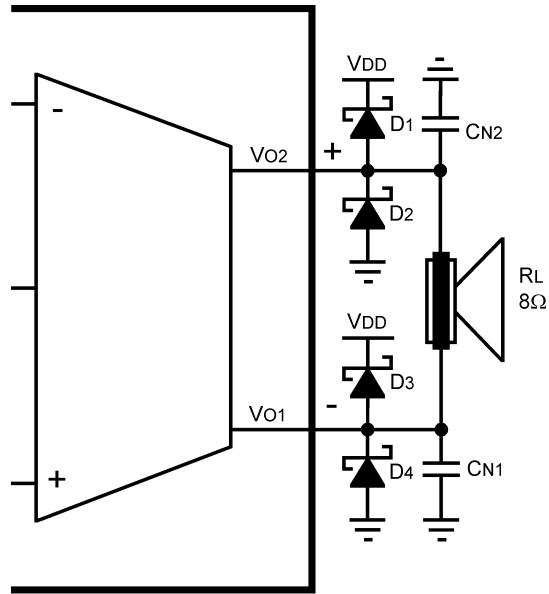
GAIN SELECTION FUNCTION

The LM4665 has fixed selectable gain to minimize external components, increase flexibility and simplify design. For a differential gain of 6dB (2V/V), the Gain Select pin should be permanently connected to V_{DD} or driven to a logic high level. For a differential gain of 12dB (4V/V), the Gain Select pin should be permanently connected to GND or driven to a logic low level. The gain of the LM4665 can be switched while the amplifier is in PLAY mode driving a load with a signal without damage to the IC. The voltage on the Gain Select pin should be switched quickly between GND (logic low) and V_{DD} (logic high) to eliminate any possible audible artifacts from appearing at the output. For typical threshold voltages for the Gain Select function, refer to the Gain Threshold Voltages graph in the **Typical Performance Characteristics** section.

INCREASING SUPPLY VOLTAGE RANGE

When using the micro SMD package (ITL), the operating supply voltage range is 2.7V - 3.8V with an 8 Ω speaker load. To increase the operating supply voltage range, four Schottky diodes (D_1 - D_4) can be used to control the over and undershoot of the output pulse waveform (See Figure 2 below). To reduce THD+N, small value capacitors in the range of 10pF - 33pF (C_{N1} & C_{N2}) can also be added as needed. The diodes should be placed as close to the micro SMD package as possible.

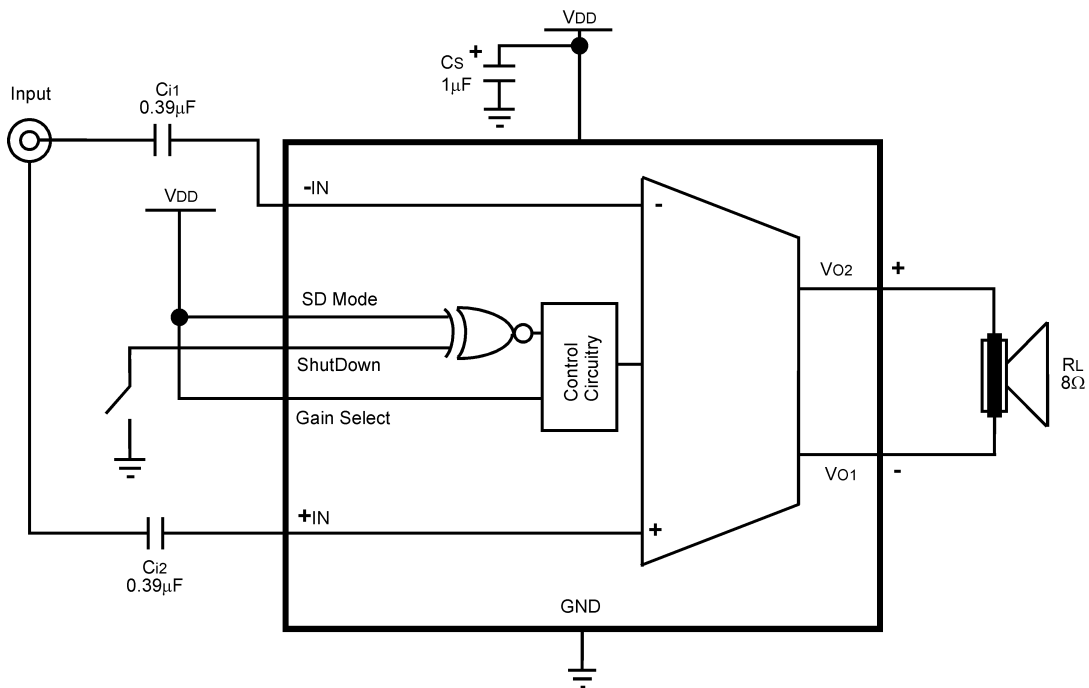
Application Information (Continued)



200270E5

FIGURE 2. Increased Supply Voltage Operating Range for the micro SMD package

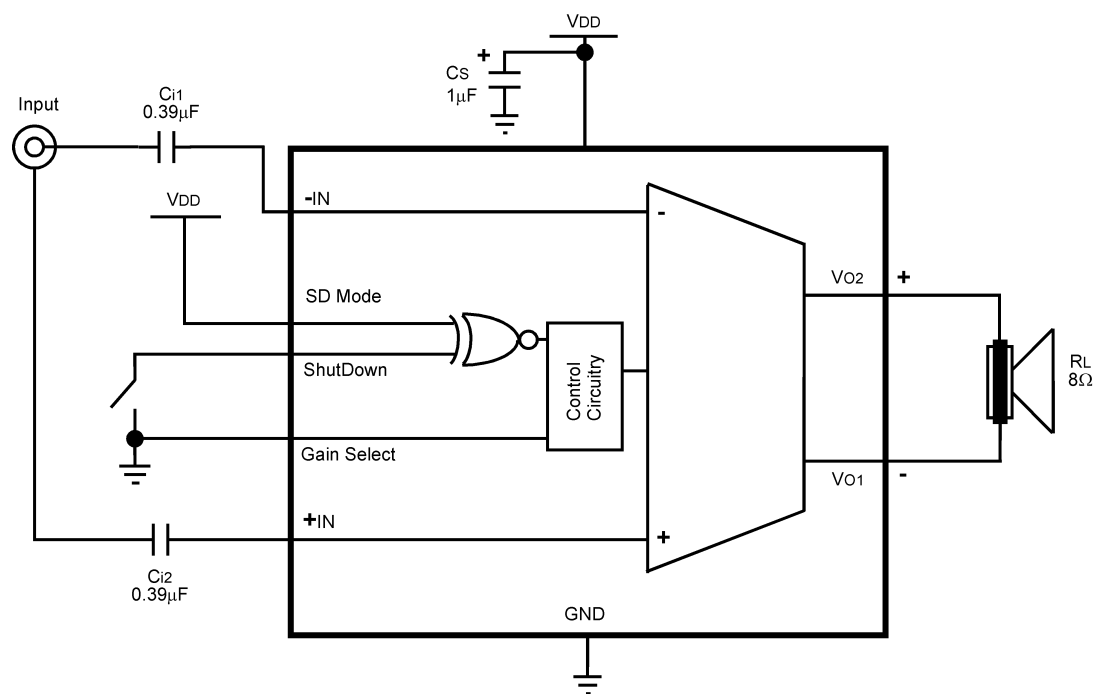
SINGLE-ENDED CIRCUIT CONFIGURATIONS



200270C4

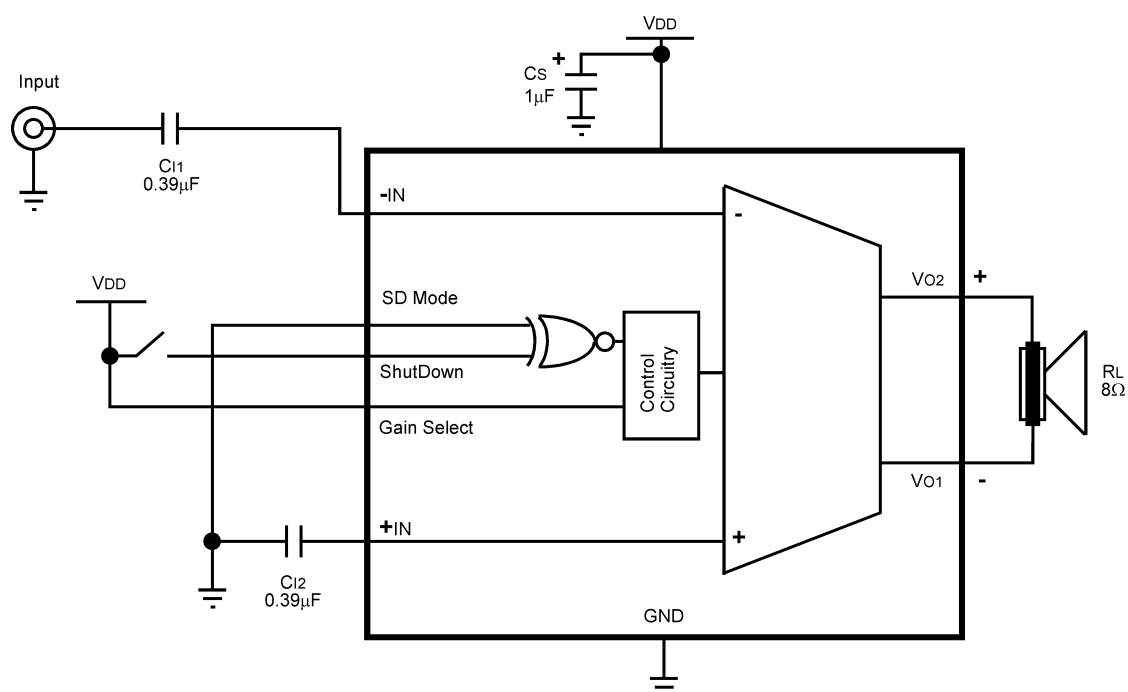
FIGURE 3. Single-Ended Input, Shutdown High and Gain of 6dB Configuration

Application Information (Continued)



200270C2

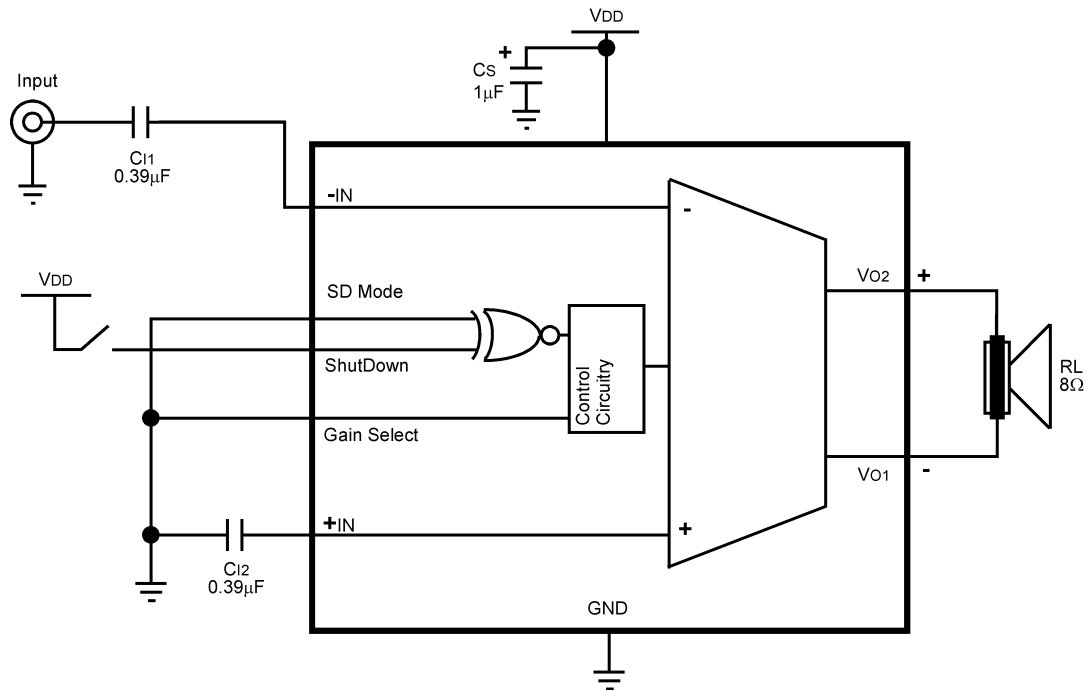
FIGURE 4. Single-Ended Input, Shutdown High and Gain of 12dB Configuration



200270C3

FIGURE 5. Single-Ended Input, Shutdown Low and Gain of 6dB Configuration

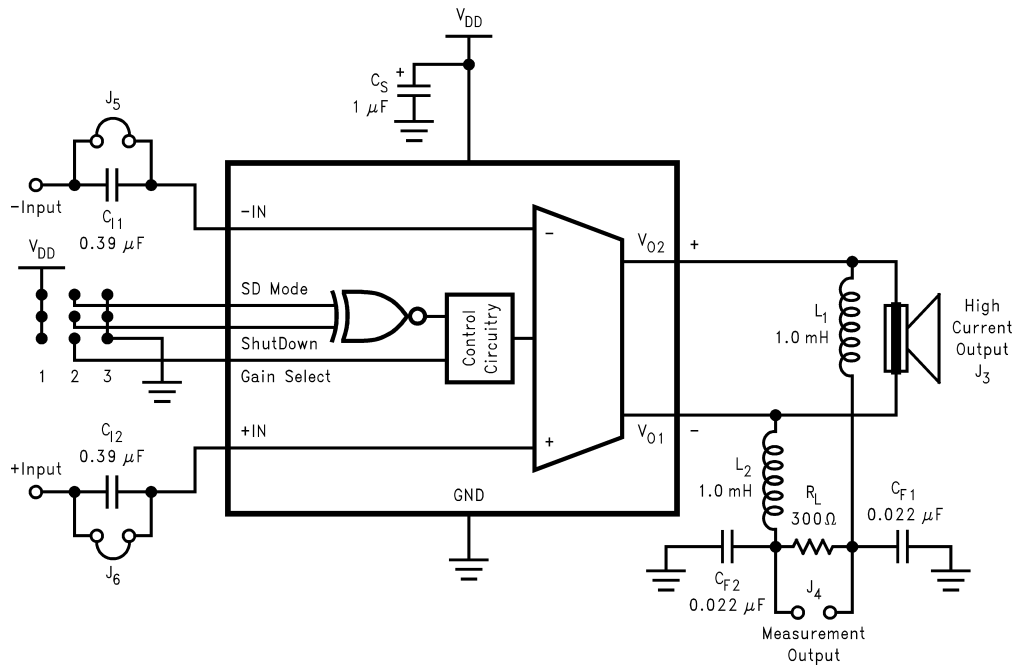
Application Information (Continued)



200270C1

FIGURE 6. Single-Ended Input, Shutdown Low and Gain of 12dB Configuration

REFERENCE DESIGN BOARD SCHEMATIC



200270B1

FIGURE 7.

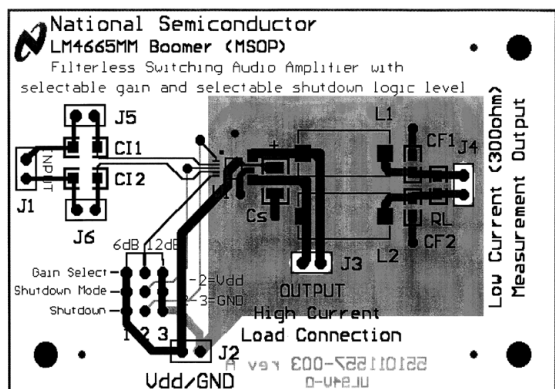
Application Information (Continued)

In addition to the minimal parts required for the application circuit, a measurement filter is provided on the evaluation circuit board so that conventional audio measurements can be conveniently made without additional equipment. This is a balanced input / grounded differential output low pass filter with a 3dB frequency of approximately 35kHz and an on board termination resistor of 300Ω (see schematic). Note that the capacitive load elements are returned to ground. This is not optimal for common mode rejection purposes, but due to the independent pulse format at each output there is a significant amount of high frequency common mode component on the outputs. The grounded capacitive filter elements attenuate this component at the board to reduce the high frequency CMRR requirement placed on the analysis instruments.

Even with the grounded filter the audio signal is still differential, necessitating a differential input on any analysis instrument connected to it. Most lab instruments that feature BNC connectors on their inputs are **NOT** differential responding because the ring of the BNC is usually grounded.

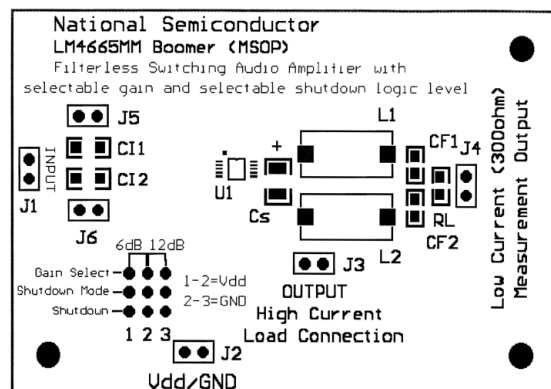
LM4665 MSOP BOARD ARTWORK

Composite View



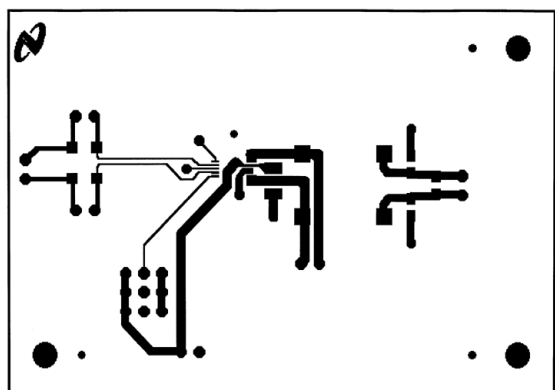
200270B2

Silk Screen



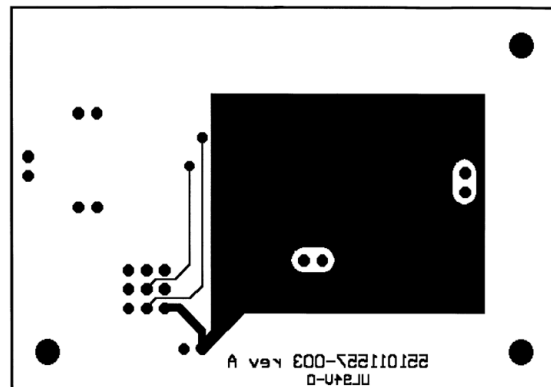
200270B3

Top Layer



200270B4

Bottom Layer



200270B5

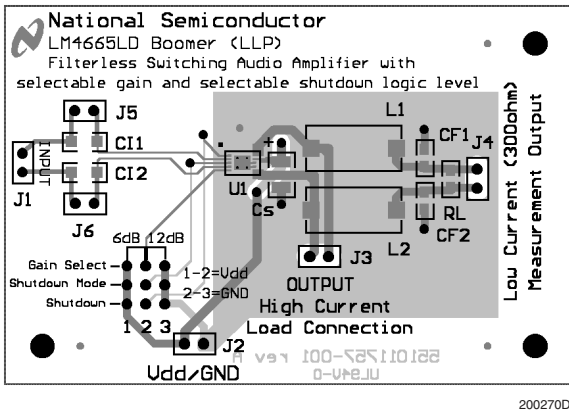
The commonly used Audio Precision analyzer is differential, but its ability to accurately reject fast pulses of 160nS width is questionable necessitating the on board measurement filter. When in doubt or when the signal needs to be single-ended, use an audio signal transformer to convert the differential output to a single ended output. Depending on the audio transformer's characteristics, there may be some attenuation of the audio signal which needs to be taken into account for correct measurement of performance.

Measurements made at the output of the measurement filter suffer attenuation relative to the primary, unfiltered outputs even at audio frequencies. This is due to the resistance of the inductors interacting with the termination resistor (300Ω) and is typically about -0.35dB (4%). In other words, the voltage levels (and corresponding power levels) indicated through the measurement filter are slightly lower than those that actually occur at the load placed on the unfiltered outputs. This small loss in the filter for measurement gives a lower output power reading than what is really occurring on the unfiltered outputs and its load.

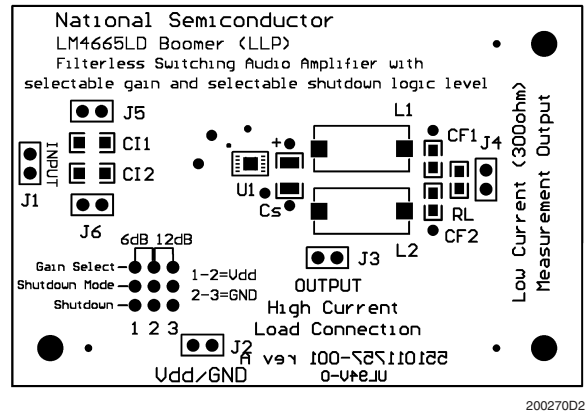
Application Information (Continued)

LM4665 LLP BOARD ARTWORK

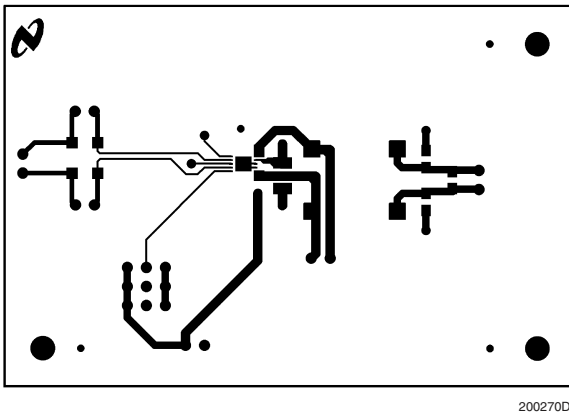
Composite View



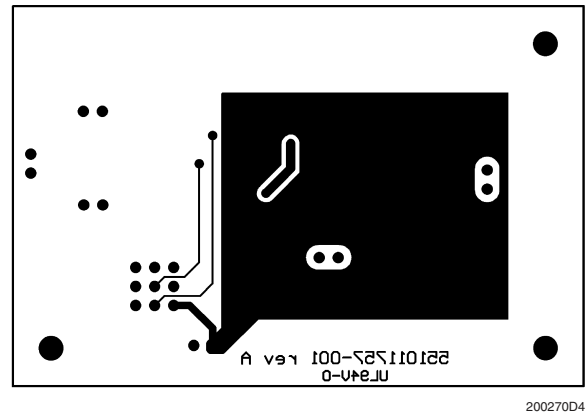
Silk Screen



Top Layer



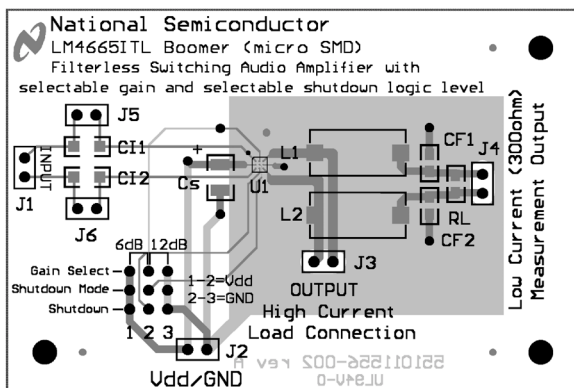
Bottom Layer



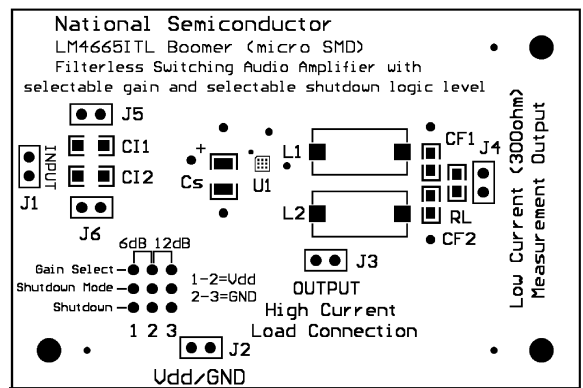
Application Information (Continued)

LM4665 micro SMD BOARD ARTWORK

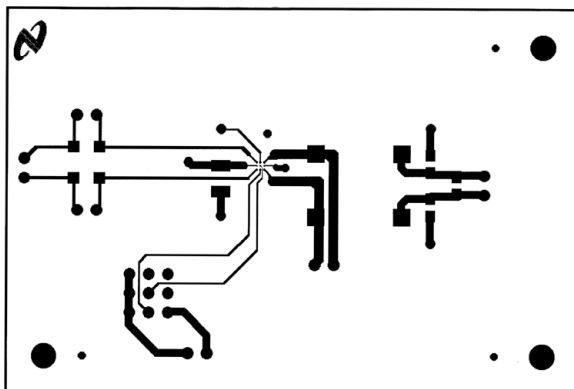
Composite View



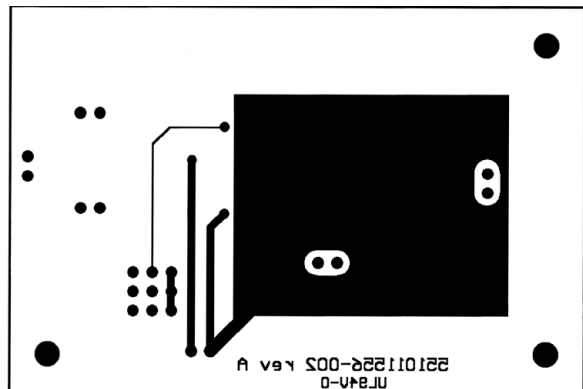
Silk Screen



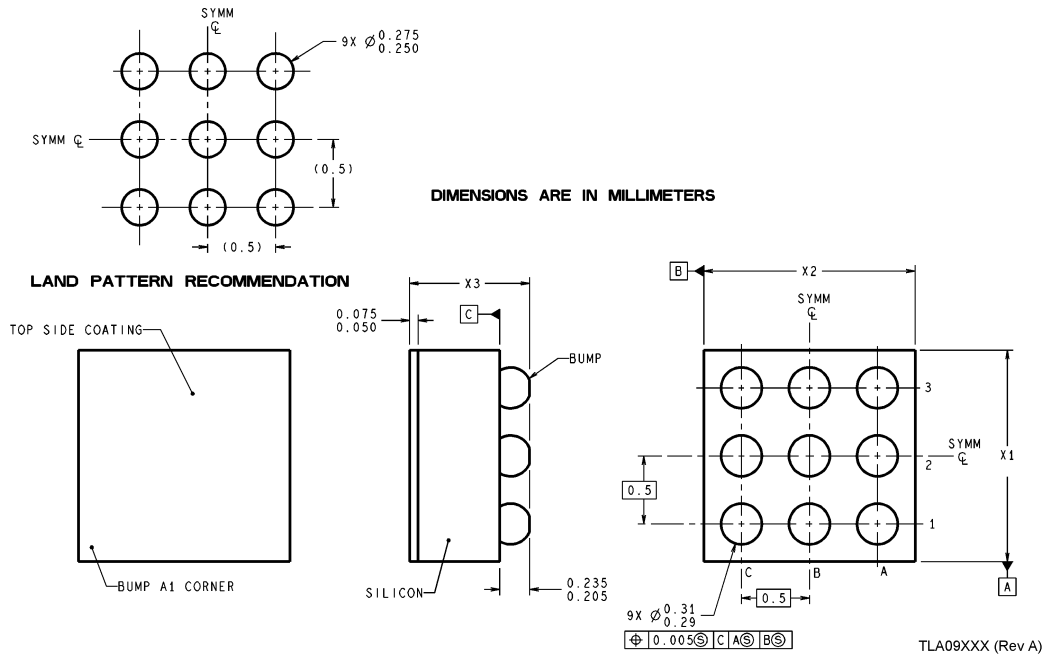
Top Layer



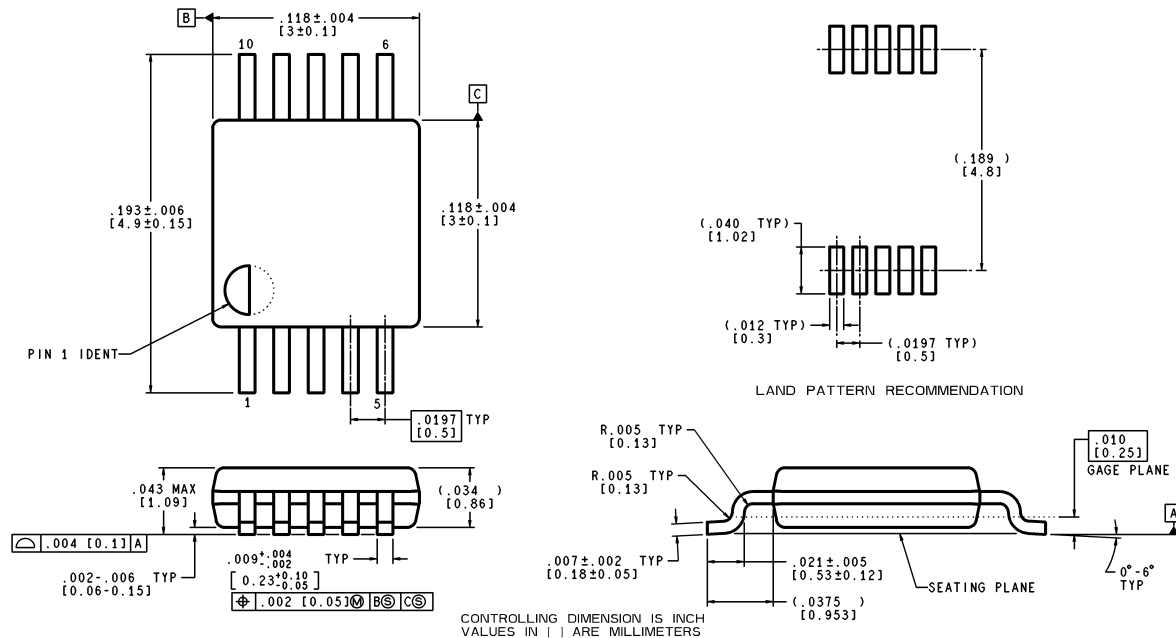
Bottom Layer



Physical Dimensions inches (millimeters) unless otherwise noted



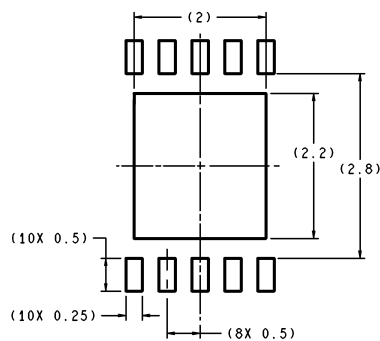
9 Bump micro SMD
Order Number LM4665ITL, LM4665ITLX
NS Package Number TLA09AAA
X₁ = 1.514 X₂ = 1.514 X₃ = 0.600



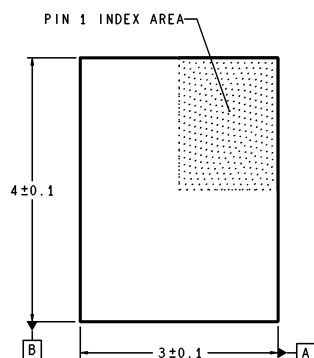
Mini Small Outline (MSOP)
Order Number LM4665MM
NS Package Number MUB10A

MUB10A (Rev A)

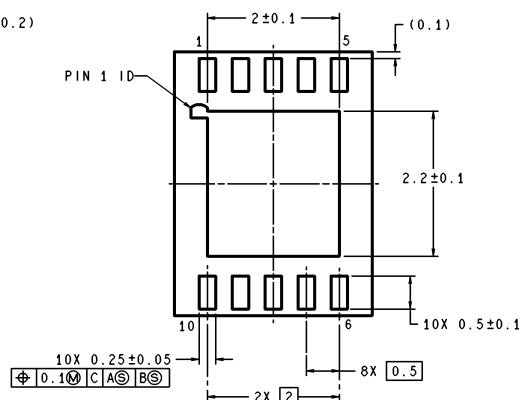
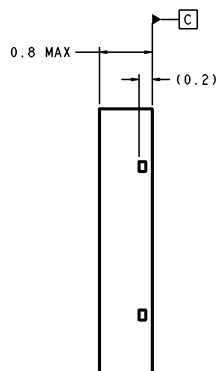
Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



RECOMMENDED LAND PATTERN
1:1 RATIO WITH PKG SOLDER PADS



DIMENSIONS ARE IN MILLIMETERS



LDA10B (Rev A)

LLP
Order Number LM4665LD
NSPackage Number LDA10B

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